MPSA27

Darlington Transistor

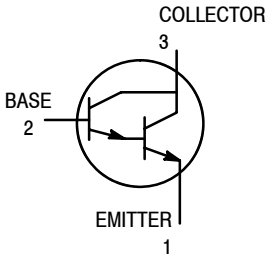
NPN Silicon

ON Semiconductor®

http://onsemi.com

Features

- These are Pb-Free Devices*



MAXIMUM RATINGS

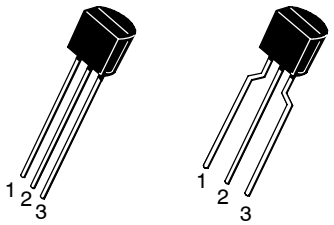
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CES}	60	Vdc
Emitter-Base Voltage	V_{EBO}	10	Vdc
Collector Current - Continuous	I_C	500	mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	625 5.0	mW mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

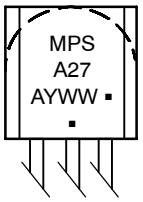
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

TO-92
CASE 29
STYLE 1



MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MPSA27G	TO-92 (Pb-Free)	5000 Units/Bulk
MPSA27RLRA	TO-92	2000/Tape & Reel
MPSA27RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector−Emitter Breakdown Voltage (I_C = 100 μAdc, V_{BE} = 0)	$V_{(BR)CES}$	60	–	–	Vdc
Collector−Base Breakdown Voltage (I_C = 100 μAdc, I_E = 0)	$V_{(BR)CBO}$	60	–	–	Vdc
Collector Cutoff Current (V_{CB} = 30 V, I_E = 0) (V_{CB} = 40 V, I_E = 0) (V_{CB} = 50 V, I_E = 0)	I_{CBO}	–	–	100	nAdc
Collector Cutoff Current (V_{CE} = 30 V, V_{BE} = 0) (V_{CE} = 40 V, V_{BE} = 0) (V_{CE} = 50 V, V_{BE} = 0)	I_{CES}	–	–	500	nAdc
Emitter Cutoff Current (V_{EB} = 10 Vdc)	I_{EBO}	–	–	100	nAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I_C = 10 mA, V_{CE} = 5.0 V) (I_C = 100 mA, V_{CE} = 5.0 V)	h_{FE}	10,000 10,000	– –	– –	–
Collector−Emitter Saturation Voltage (I_C = 100 mA, I_B = 0.1 mAdc)	$V_{CE(sat)}$	–	–	1.5	Vdc
Base−Emitter On Voltage (I_C = 100 mA, V_{CE} = 5.0 Vdc)	$V_{BE(on)}$	–	–	2.0	Vdc
SMALL−SIGNAL CHARACTERISTICS					
Small Signal Current Gain (I_C = 10 mA, V_{CE} = 5.0 V, f = 100 MHz)	h_{fe}	1.25	2.4	–	–

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

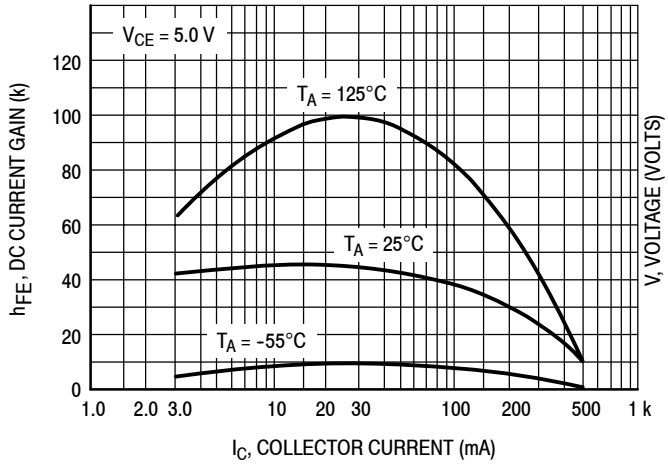


Figure 1. DC Current Gain

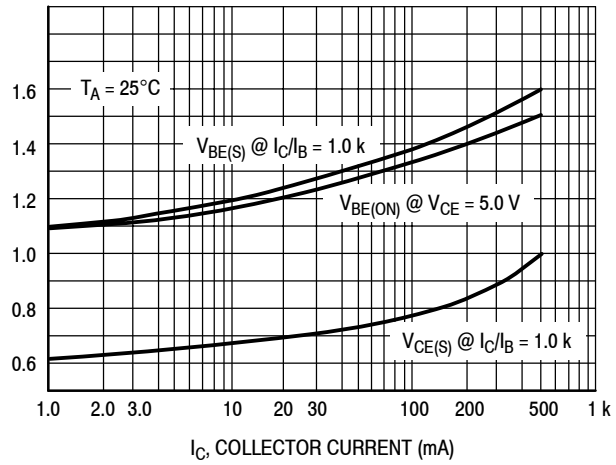


Figure 2. "ON" Voltages

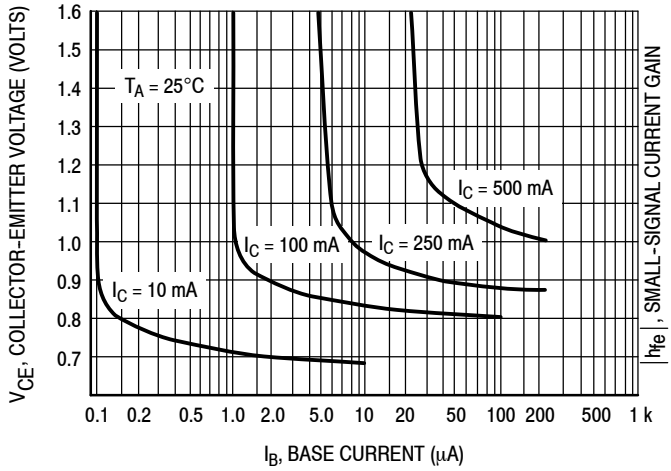


Figure 3. Collector Saturation Region

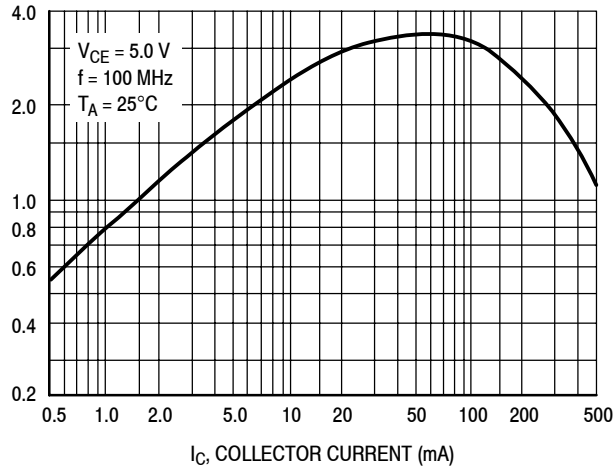


Figure 4. High Frequency Current Gain

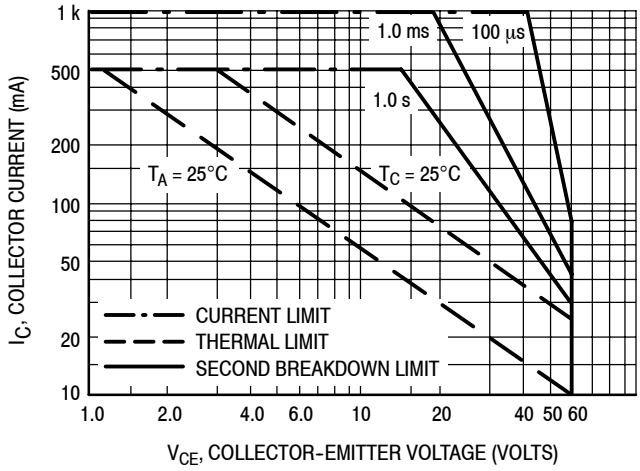
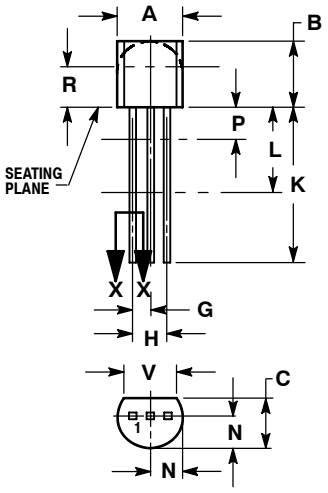


Figure 5. Active Region – Safe Operating Area

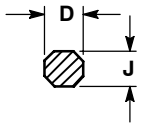
MPSA27

PACKAGE DIMENSIONS

TO−92 (TO−226)
CASE 29−11
ISSUE AM



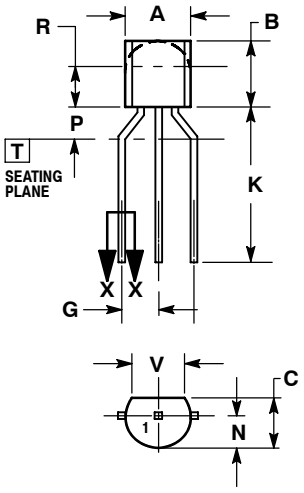
STRAIGHT LEAD
BULK PACK



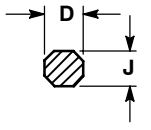
SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



BENT LEAD
TAPE & REEL
AMMO PACK



SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS	
DIM	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

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